NSN 5961-01-375-0813

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View Online at https://aerobasegroup.com/nsn/5961-01-375-0813 **Inclosure Material:** Metal **Overall Length:** 1.453 inches **Terminal Length:** 0.550 inches **Overall Diameter:** Between 0.667 inches and 0.687 inches **End Application:** 6115-01-274-7390 **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Mounting Method:** Threaded stud **Cubic Measure:** 2.154 cubic inches **Overall Width Across Flats:** 0.667 inches Thready Qty Per Inch (tpi): 28 **Thread Size:** 0.125 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 85.00 amperes collector current, dc **Special Features:** Junction pattern arrangement: pn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure:**

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Demilitarization:

No

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